

General Description

The MY035EPH uses advanced trench technology to provide excellent $R_{DS(ON)}$, low gate charge and operation with gate voltages as low as 4.5V. This device is suitable for use as a Battery protection or in other Switching application.

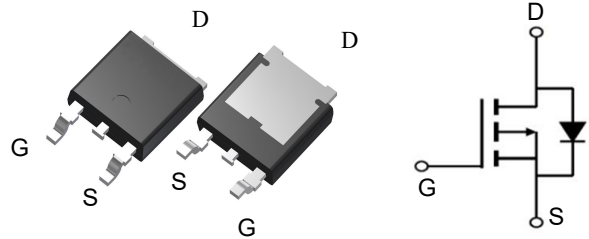


Features

V_{DSS}	-40	V
I_D	-20	A
$R_{DS(ON)}$ (at $V_{GS} = -10V$)	28	$m\Omega$
$R_{DS(ON)}$ (at $V_{GS} = -4.5V$)	33	$m\Omega$

Application

- Battery protection
- Load switch
- Uninterruptible power supply



Package Marking and Ordering Information

Product ID	Pack	Marking	Qty(PCS)
MY035EPH	TO-252-2L	MY035EPH	2500

Absolute Maximum Ratings ($T_A = 25^\circ\text{C}$ unless otherwise noted)

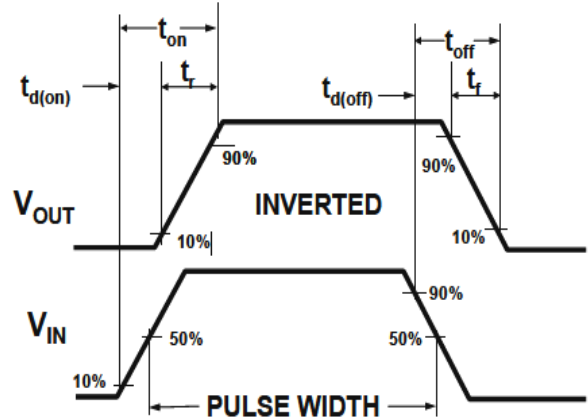
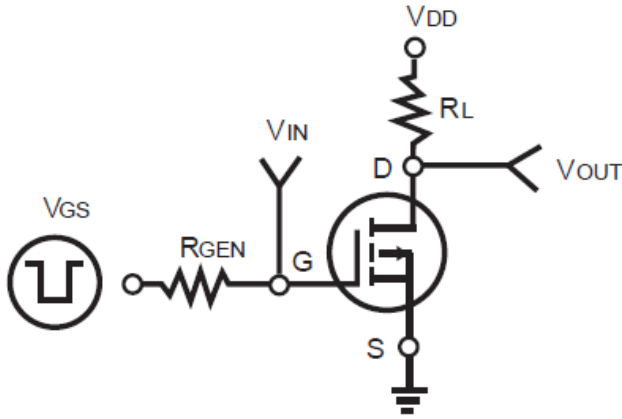
Symbol	Parameter	Value	Unit
V_{DS}	Drain-Source Voltage ($V_{GS}=0V$)	-40	V
V_{GS}	Gate-Source Voltage ($V_{DS}=0V$)	± 20	V
I_D	Drain Current-Continuous($T_C=25^\circ\text{C}$)	-20	A
	Drain Current-Continuous($T_C=100^\circ\text{C}$)	-15	A
I_{DM} (pluse)	(Note 1) Drain Current-Continuous@ Current-Pulsed	-80	A
P_D	Maximum Power Dissipation($T_C=25^\circ\text{C}$)	37.5	W
	Maximum Power Dissipation($T_C=100^\circ\text{C}$)	19	W
T_J, T_{STG}	Operating Junction and Storage Temperature Range	-55 To 175	$^\circ\text{C}$
R_{JC}	Thermal Resistance, Junction-to-Case	4	$^\circ\text{C}/\text{W}$

Electrical Characteristics (T_A=25 °C, unless otherwise noted)

Symbol	Parameter	Conditions	Min	Typ	Max	Unit
BV _{DSS}	Drain-Source Breakdown Voltage	V _{GS} =0V, I _D =-250μA	-40			V
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =-32V, V _{GS} =0V			-1	μA
I _{GSS}	Gate-Body Leakage Current	V _{GS} =±20V, V _{DS} =0V			±100	nA
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =V _{GS} , I _D =-250μA	-1	-2	-3	V
g _{FS}	Forward Transconductance	V _{DS} =-5V, I _D =-10A		25		S
R _{DS(ON)}	Drain-Source On-State Resistance	V _{GS} =-10V, I _D =-20A		25	35	mΩ
		V _{GS} =-4.5V, I _D =-10A		35	47	mΩ
C _{iss}	Input Capacitance	V _{DS} =-25V, V _{GS} =0V, f=1.0MHz		840		pF
C _{oss}	Output Capacitance			92		pF
C _{rss}	Reverse Transfer Capacitance			60		pF
t _{d(on)}	Turn-on Delay Time	V _{GS} =-10V, V _{DS} =- 20V, R _L =1.6 , R _{GEN} =3		5		nS
t _r	Turn-on Rise Time			12		nS
t _{d(off)}	Turn-Off Delay Time			20		nS
t _f	Turn-Off Fall Time			4.5		nS
Q _g	Total Gate Charge	V _{GS} =-10V, V _{DS} =-20V, I _D =-15A		20		nC
Q _{gs}	Gate-Source Charge			2.5		nC
Q _{gd}	Gate-Drain Charge			4.5		nC
I _{SD}	Source-Drain Current(Body Diode)				-20	A
V _{SD}	Forward on Voltage	V _{GS} =0V, I _S =-20A			-1.2	V

Notes 1.Repetitive Rating: Pulse width limited by maximum junction temperature

Typical Characteristics



TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS (Curves)

Figure1. Power Dissipation

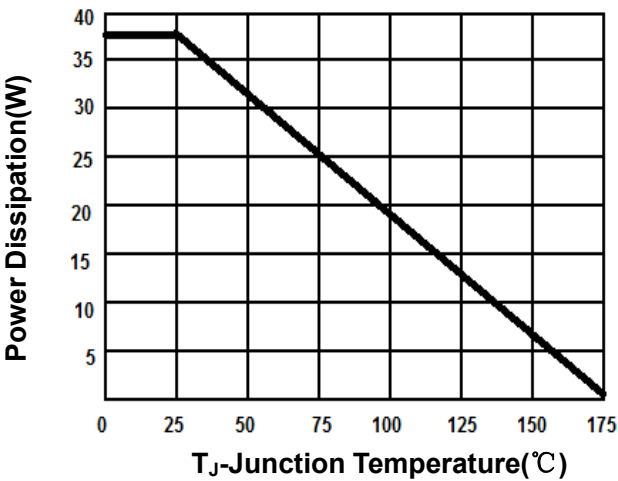


Figure2. Drain Current

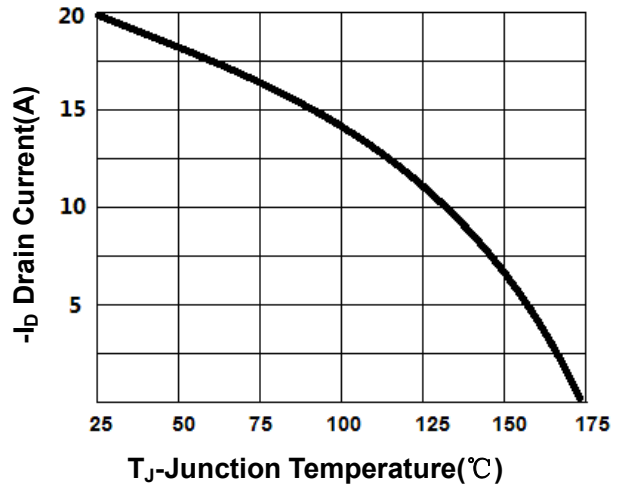


Figure3. Output Characteristics

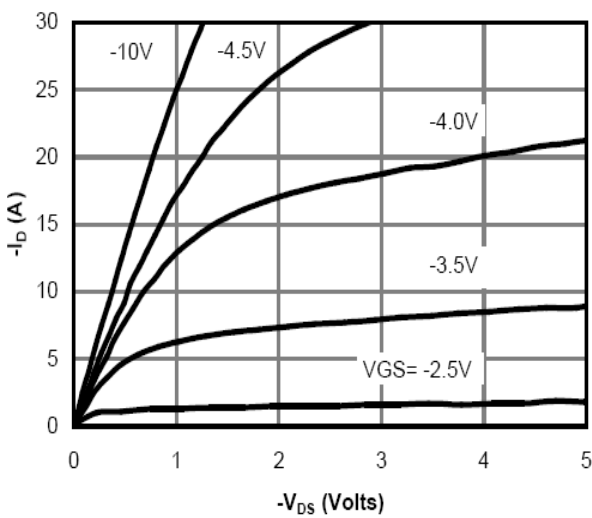


Figure4. Transfer Characteristics

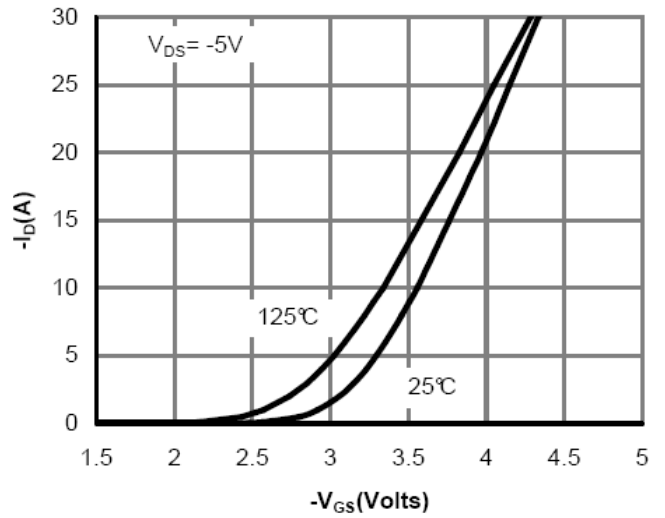


Figure5. Capacitance

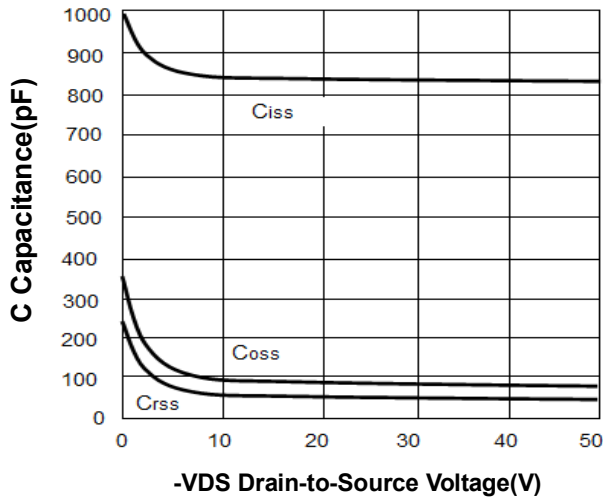


Figure6. $R_{DS(ON)}$ vs Junction Temperature

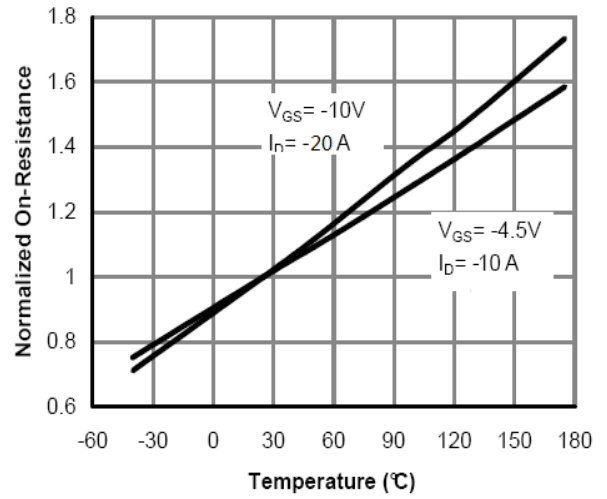


Figure7. $V_{GS(th)}$ vs Junction Temperature

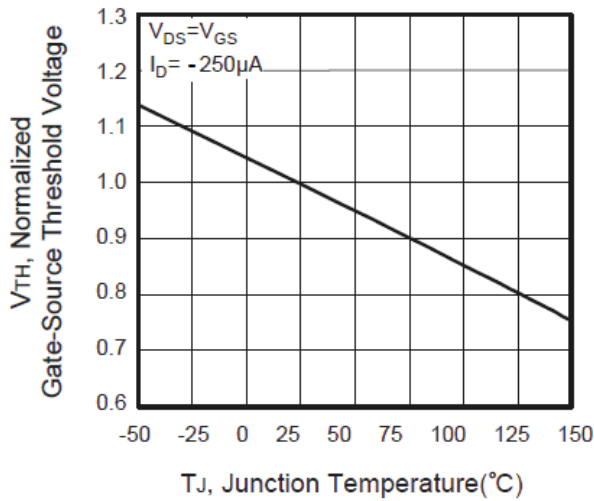


Figure8. Gate Charge Waveforms

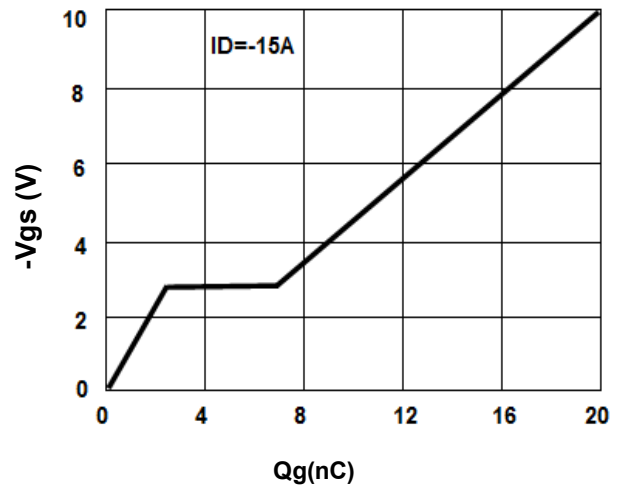
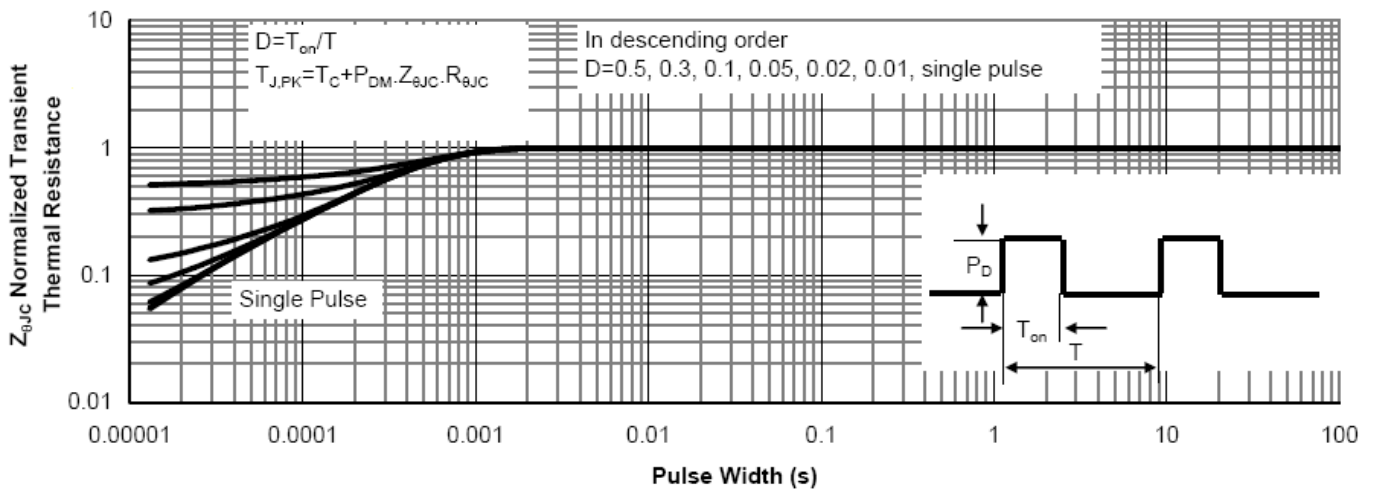
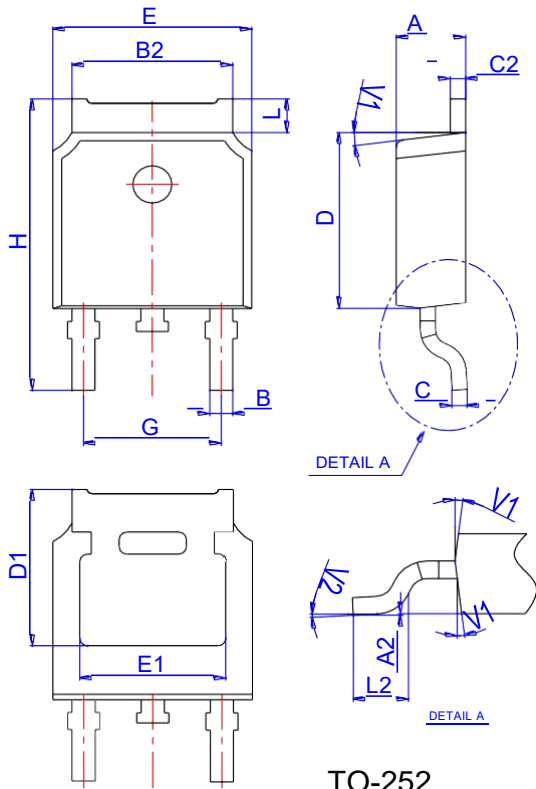


Figure9. Normalized Maximum Transient Thermal Impedance

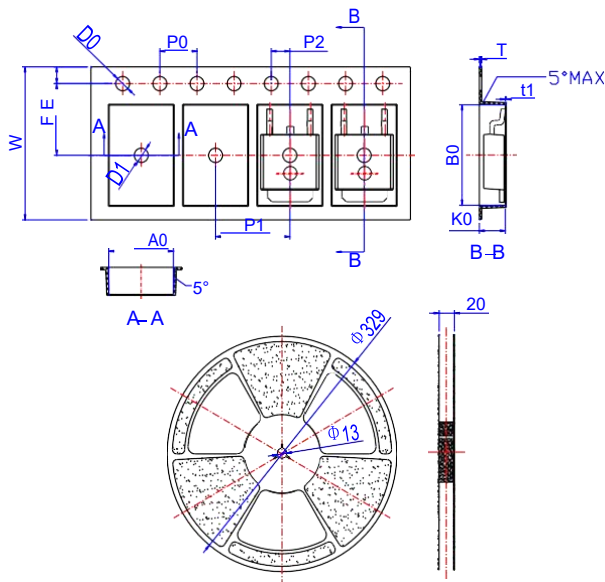


Package Mechanical Data-TO-252-JQ Single



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A	2.10		2.50	0.083		0.098
A2	0		0.10	0		0.004
B	0.66		0.86	0.026		0.034
B2	5.18		5.48	0.202		0.216
C	0.40		0.60	0.016		0.024
C2	0.44		0.58	0.017		0.023
D	5.90		6.30	0.232		0.248
D1	5.30REF			0.209REF		
E	6.40		6.80	0.252		0.268
E1	4.63			0.182		
G	4.47		4.67	0.176		0.184
H	9.50		10.70	0.374		0.421
L	1.09		1.21	0.043		0.048
L2	1.35		1.65	0.053		0.065
V1		7°			7°	
V2	0°		6°	0°		6°

Reel Specification-TO-252



Ref.	Dimensions					
	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
W	15.90	16.00	16.10	0.626	0.630	0.634
E	1.65	1.75	1.85	0.065	0.069	0.073
F	7.40	7.50	7.60	0.291	0.295	0.299
D0	1.40	1.50	1.60	0.055	0.059	0.063
D1	1.40	1.50	1.60	0.055	0.059	0.063
P0	3.90	4.00	4.10	0.154	0.157	0.161
P1	7.90	8.00	8.10	0.311	0.315	0.319
P2	1.90	2.00	2.10	0.075	0.079	0.083
A0	6.85	6.90	7.00	0.270	0.271	0.276
B0	10.45	10.50	10.60	0.411	0.413	0.417
K0	2.68	2.78	2.88	0.105	0.109	0.113
T	0.24		0.27	0.009		0.011
t1	0.10			0.004		
10P0	39.80	40.00	40.20	1.567	1.575	1.583